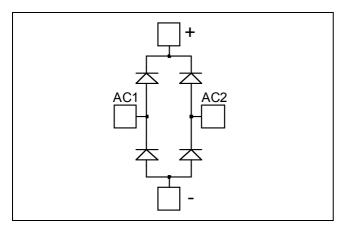


APTDF100H20G

Diode Full Bridge Power Module



$V_{RRM} = 200V$ $I_{C} = 100A$ @ Tc = 80°C

Application

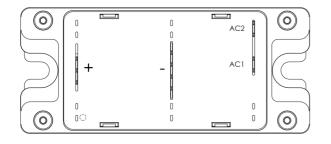
- Uninterruptible Power Supply (UPS)
- Induction heating
- Welding equipment
- High speed rectifiers

Features

- Ultra fast recovery times
- Soft recovery characteristics
- High blocking voltage
- High current
- Low leakage current
 - Very low stray inductance - Symmetrical design
 - Lead frames for power connections
- High level of integration

Benefits

- Outstanding performance at high frequency operation
- Low losses
- Low noise switching
- Solderable terminals for easy PCB mounting
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- RoHS Compliant



Absolute maximum ratings

Symbol	Parameter			Max ratings	Unit			
V _R	Maximum DC reverse Voltage	Maximum DC reverse Voltage			200	V		
V _{RRM}	Maximum Peak Repetitive Reverse Voltage				200	v		
I _{F(AV)}	Maximum Average Forward	Duty cycle = 50%		$T_C = 25^{\circ}C$	145			
	Current			$T_C = 80^{\circ}C$	100	Δ		
I _{F(RMS)}	RMS Forward Current	Duty cycle = 50%		Duty cycle = 50% T _C		$T_C = 45^{\circ}C$	145	11
I _{FSM}	Non-Repetitive Forward Surge Cu	urrent 8.3ms		$T_C = 45^{\circ}C$	500			

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com

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All ratings (a) $T_j = 25^{\circ}C$ unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit	
\mathbf{V}_{F}		$I_{\rm F} = 100 {\rm A}$			1.0	1.1	
	Diode Forward Voltage	$I_{\rm F} = 200 {\rm A}$			1.4		V
		$I_{\rm F} = 100 {\rm A}$	$T_j = 125^{\circ}C$		0.9		
т	Maximum Payana Laskaga Cumant	$V_{\rm p} = 200 V$	$T_i = 25^{\circ}C$			250	
I _{RM}	Maximum Reverse Leakage Current		$T_{j} = 125^{\circ}C$			500	μA
CT	Junction Capacitance	$V_R = 200V$			400		pF

Dynamic Characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
t _{rr}	Reverse Recovery Time	$I_F=1A, V_R=30V$ di/dt = 100A/ μ s	$T_j = 25^{\circ}C$		39		ns
t _{rr}	Reverse Recovery Time		$T_j = 25^{\circ}C$		60		ns
۲r	Reverse Recovery Time		$T_{j} = 125^{\circ}C$		110		
Q _{rr}	Reverse Recovery Charge	$I_{\rm F} = 100 \text{A}$ $V_{\rm R} = 133 \text{V}$ $di/dt = 200 \text{A}/\mu \text{s}$	$T_j = 25^{\circ}C$		200		nC
Qrr	Reverse Recovery Charge		$T_{j} = 125^{\circ}C$		840		
I	Reverse Recovery Current		$T_j = 25^{\circ}C$		6		A
I _{RRM}	Reverse Recovery Current		$T_j = 125^{\circ}C$		15		
t _{rr}	Reverse Recovery Time	$I_F = 100A$ $V_R = 133V$ $di/dt = 1000A/\mu s$			80		ns
Q _{rr}	Reverse Recovery Charge		$T_j = 125^{\circ}C$		1.91		μC
I _{RRM}	Reverse Recovery Current				44		А

Thermal and package characteristics

Symbol	Characteristic			Min	Тур	Max	Unit
R _{thJC}	Junction to Case Thermal Resistance					0.55	°C/W
VISOL	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
T _J	Operating junction temperature range			-40		150	v °C
T _{STG}	Storage Temperature Range			-40		125	
T _C	Operating Case Temperature			-40		100	
Torque	Mounting torque	To Heatsink	M5	2.5		4.7	N.m
Wt	Package Weight					160	g

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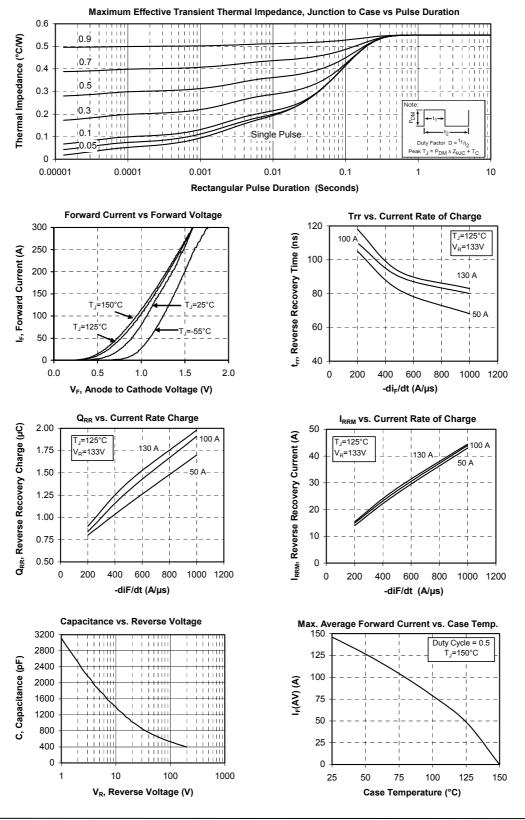
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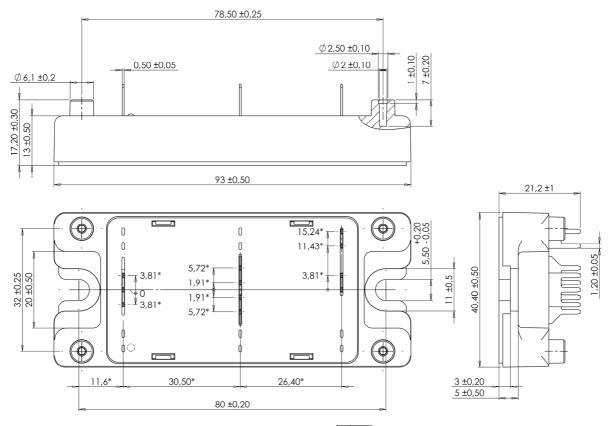
Typical Performance Curve



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SP4 Package outline (dimensions in mm)



ALL DIMENSIONS MARKED "*" ARE TOLERANCED AS : 🔶 Ø 1

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